

SR4030PT thru SR40150PT

SCHOTTKY BARRIER RECTIFIERS

REVERSE VOLTAGE - **30** to **150**Volts FORWARD CURRENT - **40.0** Amperes

FEATURES

- Metal of silicon rectifier , majority carrier conduction
- Guard ring for transient protection
- Low power loss, high efficiency
- High current capability, low VF
- High surge capacity
- Plastic package has UL flammability

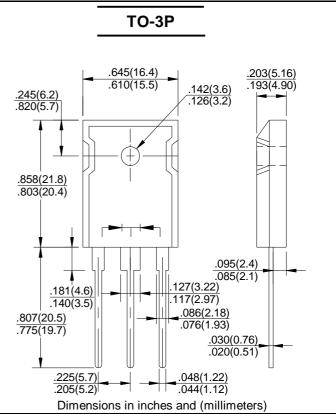
classification 94V-0

•For use in low voltage, high frequency inverters, free

wheeling, and polarity protection applications

MECHANICAL DATA

- •Case: TO-3P molded plastic
- Polarity: As marked on the body
- •Weight: 0.2ounces,5.6 grams
- Mounting position :Any



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

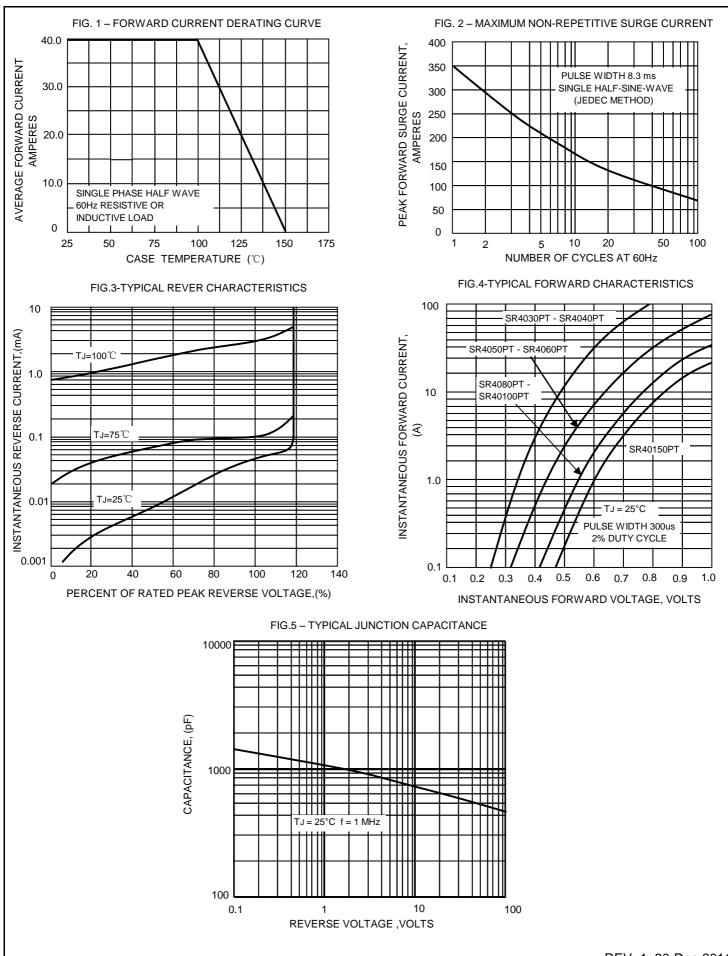
Rating at 25°C ambient temperature unless otherwise specified. Single phase, half wave ,60Hz, resistive or inductive load. For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	SR 4030PT	SR 4040PT	SR 4050PT	SR 4060PT	SR 4080PT	SR 40100PT	SR 40150PT	UNIT
Maximum Recurrent Peak Reverse Voltage	Vrrm	30	40	50	60	80	100	150	V
Maximum RMS Voltage	VRMS	21	28	35	42	56	70	105	V
Maximum DC Blocking Voltage	VDC	30	40	50	60	80	100	150	V
Maximum Average Forward Rectified Current (See Fig.1) @Tc=100℃	l(AV)	40							А
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Super Imposed on Rated Load (JEDEC Method)	IFSM	350							A
Peak Forward Voltage at 20.0A DC	VF	0.55		0.	0.70 0.		.85	0.95	V
Maximum DC Reverse Current@Tj=25°Cat Rated DC Bolcking Voltage@Tj=100°C	lr	1.0 100							mA
Typical Junction Capacitance (Note1)	CJ	800							pF
Typical Thermal Resistance (Note2)	Rejc	1.4							°C/W
Operating Temperature Range	TJ	-55 to + 150							°C
Storage Temperature Range	Tstg	-55 to + 150							°C

NOTES: 1.Measured at 1.0 MHz and applied reverse voltage of 4.0VDC.

2. Thermal resistance junction to case.

RATING AND CHARACTERTIC CURVES SR4030PT thru SR40150PT



REV. 1, 30-Dec-2011